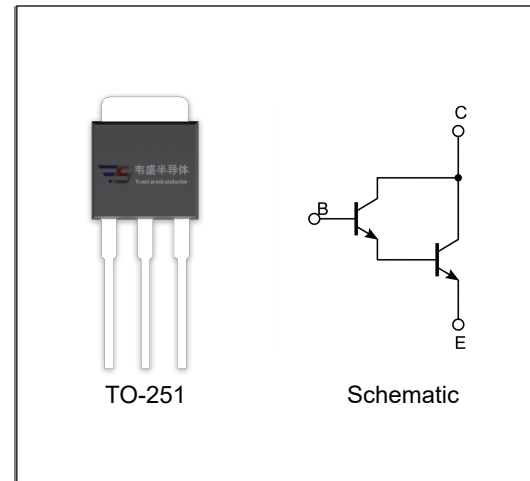


## MJD122 TRANSISTOR (NPN)

### FEATURES

- High DC Current Gain
- Electrically Similar to Popular TIP122
- Built-in a Damper Diode at E-C



### MAXIMUM RATINGS (T<sub>a</sub>=25°C unless otherwise noted)

| Symbol                            | Parameter                                        | Value   | Unit |
|-----------------------------------|--------------------------------------------------|---------|------|
| V <sub>CBO</sub>                  | Collector-Base Voltage                           | 100     | V    |
| V <sub>CEO</sub>                  | Collector-Emitter Voltage                        | 100     | V    |
| V <sub>EBO</sub>                  | Emitter-Base Voltage                             | 5       | V    |
| I <sub>C</sub>                    | Collector Current -Continuous                    | 8       | A    |
| P <sub>C</sub>                    | Collector Dissipation                            | 1.5     | W    |
| T <sub>J</sub> , T <sub>stg</sub> | Operation Junction and Storage Temperature Range | -55-150 | °C   |

| Parameter                            | Symbol                    | Test conditions               | Min  | Typ | Max   | Unit    |
|--------------------------------------|---------------------------|-------------------------------|------|-----|-------|---------|
| Collector-base breakdown voltage     | $V_{(BR)CBO}$             | $I_C=1mA, I_E=0$              | 100  |     |       | V       |
| Collector-emitter breakdown voltage  | $V_{(BR)CEO}$             | $I_C=30mA, I_B=0$             | 100  |     |       | V       |
| Emitter-base breakdown voltage       | $V_{(BR)EBO}$             | $I_E=3mA, I_C=0$              | 5    |     |       | V       |
| Collector cut-off current            | $I_{CBO}$                 | $V_{CB}=100V, I_E=0$          |      |     | 10    | $\mu A$ |
| Collector-emitter cut-off current    | $I_{CEO}$                 | $V_{CE}=50V, I_B=0$           |      |     | 10    | $\mu A$ |
| Emitter cut-off current              | $I_{EBO}$                 | $V_{EB}=5V, I_C=0$            |      |     | 2     | mA      |
| DC current gain                      | $h_{FE(2)}$               | $V_{CE}=4V, I_C=4A$           | 1000 |     | 12000 |         |
|                                      | $h_{FE(3)}$               | $V_{CE}=4V, I_C=8A$           | 100  |     |       |         |
| Collector-emitter saturation voltage | $V_{CE(sat) \text{ (1)}}$ | $I_C=4A, I_B=16mA$            |      |     | 2     | V       |
|                                      | $V_{CE(sat) \text{ (2)}}$ | $I_C=8A, I_B=80mA$            |      |     | 4     | V       |
| Base-emitter saturation voltage      | $V_{BE(sat)}$             | $I_C=8A, I_B=80mA$            |      |     | 4.5   | V       |
| Base-emitter voltage*                | $V_{BE}$                  | $V_{CE}=4V, I_C=4A$           |      |     | 2.8   | V       |
| Collector output capacitance         | $C_{ob}$                  | $V_{CB}=10V, I_E=0, f=0.1MHz$ |      |     | 200   | pF      |

